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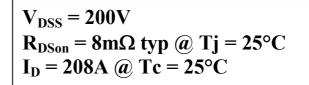


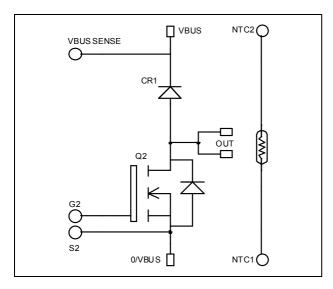






# Boost chopper MOSFET Power Module





G2 🛭

S2 🛱

G2 0

OUT

NTC2

NTC1

O/VBUS

#### **Application**

- AC and DC motor control
- Switched Mode Power Supplies
- Power Factor Correction

#### **Features**

- Power MOS 7<sup>®</sup> MOSFETs
  - Low R<sub>DSon</sub>
  - Low input and Miller capacitance
  - Low gate charge
  - Avalanche energy rated
  - Very rugged
- Kelvin source for easy drive
- Very low stray inductance
  - Symmetrical design
  - Lead frames for power connections
- Internal thermistor for temperature monitoring
- High level of integration



- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- RoHS compliant

#### **Absolute maximum ratings**

0

**VBUS** 

**⋒** ∨BUS

Symbol	Parameter	Max ratings	Unit	
$V_{ m DSS}$	Drain - Source Breakdown Voltage		200	V
т	Continuous Drain Current $T_c = 2$		208	
$I_{D}$	Continuous Drain Current	$T_c = 80^{\circ}C$	155	A
$I_{DM}$	Pulsed Drain current	ulsed Drain current		
$V_{GS}$	Gate - Source Voltage		±30	V
R <sub>DSon</sub>	Drain - Source ON Resistance		10	mΩ
$P_{D}$	Maximum Power Dissipation $T_c = 25^{\circ}C$		781	W
$I_{AR}$	Avalanche current (repetitive and non repetitive)		100	A
E <sub>AR</sub>	Repetitive Avalanche Energy		50	mJ
$E_{AS}$	Single Pulse Avalanche Energy		3000	1113

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



### All ratings @ $T_j = 25^{\circ}C$ unless otherwise specified

### **Electrical Characteristics**

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
ī	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 200V$ $T_j = 25^{\circ}C$			150	^
$I_{ m DSS}$		$V_{GS} = 0V, V_{DS} = 160V$ $T_j = 125^{\circ}C$			750	μA
R <sub>DS(on)</sub>	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 104A$		8	10	mΩ
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 5mA$	3		5	V
$I_{GSS}$	Gate – Source Leakage Current	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{ V}$			±150	nA

**Dynamic Characteristics** 

·	Characteristic	Test Conditions	Min	Тур	Max	Unit
$C_{iss}$	Input Capacitance	$V_{GS} = 0V$		14.4		
$C_{oss}$	Output Capacitance	$V_{\rm DS} = 25 V$		4.66		nF
$C_{rss}$	Reverse Transfer Capacitance	f=1MHz		0.29		
$Q_{\mathrm{g}}$	Total gate Charge	$V_{GS} = 10V$		280		
$Q_{\mathrm{gs}}$	Gate – Source Charge	$V_{Bus} = 100V$		106		пC
$Q_{gd}$	Gate – Drain Charge	$I_D = 208A$		134		
$T_{d(on)}$	Turn-on Delay Time	Inductive switching @ 125°C		32		
$T_{\rm r}$	Rise Time	$V_{GS} = 15V$		64		
$T_{d(off)}$	Turn-off Delay Time	$V_{\text{Bus}} = 133V$ $I_{\text{D}} = 208A$		88		ns
$T_{\mathrm{f}}$	Fall Time	$R_G = 2.5\Omega$		116		
Eon	Turn-on Switching Energy	Inductive switching @ 25°C		1698		1
$E_{\text{off}}$	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 133V$ $I_D = 208A, R_G = 2.5\Omega$		1858		μJ
Eon	Turn-on Switching Energy	Inductive switching @ 125°C $V_{GS} = 15V, V_{Bus} = 133V$ $I_D = 208A, R_G = 2.5\Omega$		1872		
E <sub>off</sub>	Turn-off Switching Energy			1972		μJ

### Chopper diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
$V_{RRM}$	Maximum Peak Repetitive Reverse Voltage			200			V
$I_{RM}$	Maximum Reverse Leakage Current	V <sub>R</sub> =200V	$T_{\rm j} = 25^{\circ}{\rm C}$			500	μΑ
$I_{\mathrm{F}}$	DC Forward Current		$T_{\rm j} = 125^{\circ} \text{C}$ $T_{\rm c} = 80^{\circ} \text{C}$		180	750	A
1 <sub>F</sub>	DC Forward Current		$T_c = 80$ C				Α
	Diode Forward Voltage	$I_F = 180A$			1.1	1.15	
$V_{\rm F}$		$I_{\rm F} = 360A$			1.4		V
		$I_F = 180A$	$T_j = 125^{\circ}C$		0.9		
t <sub>rr</sub>	Reverse Recovery Time	- ,	$T_j = 25$ °C		31		ng
			$T_{j} = 125^{\circ}C$		60		ns
Q <sub>rr</sub>	Reverse Recovery Charge	$V_R = 133V$ $di/dt = 600A/\mu s$	$T_j = 25$ °C		180		пС
			$T_j = 125$ °C		750		пС



### Thermal and package characteristics

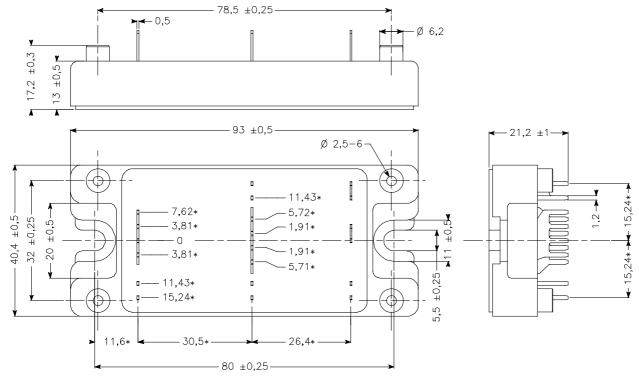
Symbol	Characteristic			Min	Typ	Max	Unit
D	Liunction to Case Thermal Resistance		Transistor			0.16	°C/W
$R_{thJC}$			Diode			0.32	C/ VV
$V_{ISOL}$	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
$T_{J}$	Operating junction temperature range			-40		150	
$T_{STG}$	Storage Temperature Range		-40		125	°C	
$T_{\rm C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque	To Heatsink	M5	2.5		4.7	N.m
Wt	Package Weight				160	g	

Temperature sensor NTC (see application note APT0406 on www.microsemi.com for more information).

Symbol	Characteristic	Min	Тур	Max	Unit
R <sub>25</sub>	Resistance @ 25°C		50		kΩ
${ m B}_{25/85}$	$T_{25} = 298.15 \text{ K}$		3952		K

$$R_T = \frac{R_{25}}{\exp\left[B_{25/85}\left(\frac{1}{T_{25}} - \frac{1}{T}\right)\right]}$$
 T: Thermistor temperature R<sub>T</sub>: Thermistor value at T

#### SP4 Package outline (dimensions in mm)

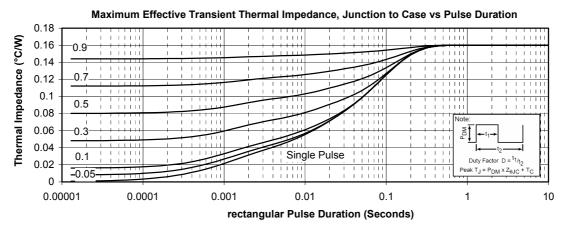


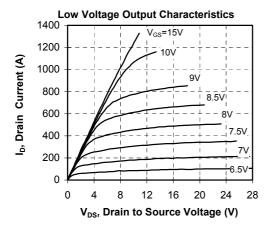
ALL DIMENSIONS MARKED "  $^*$  " ARE TOLERENCED AS :  $\boxed{\oplus \varnothing 1}$ 

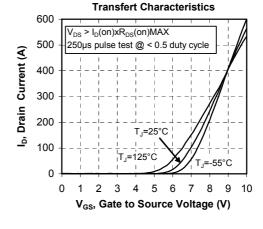
See application note APT0501 - Mounting Instructions for SP4 Power Modules on www.microsemi.com

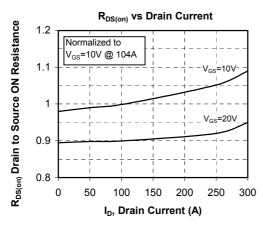


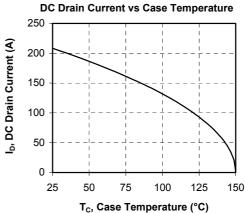
#### **Typical Performance Curve**



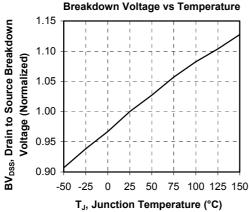


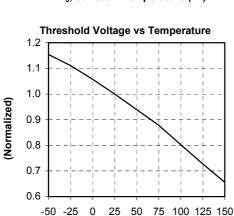






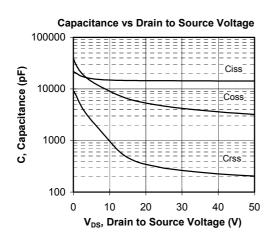


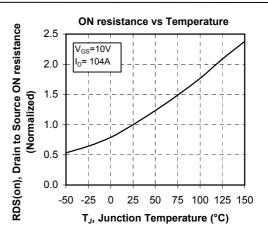


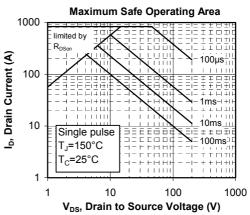


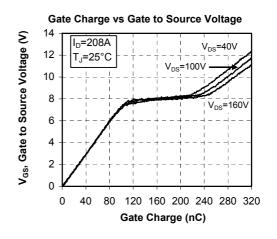
T<sub>C</sub>, Case Temperature (°C)

V<sub>GS</sub>(TH), Threshold Voltage

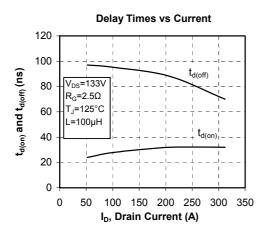


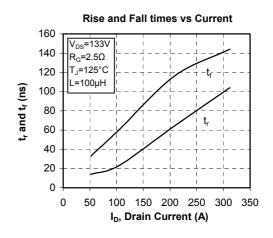


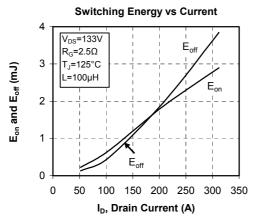


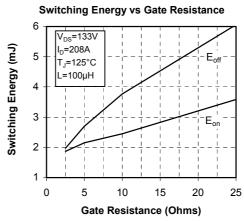


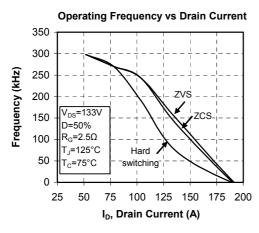


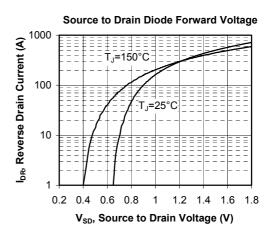












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